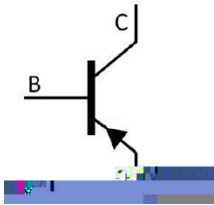


Rev. F Aug.-2018

SOT-23 PNP Silicon PNP transistor in a SOT-23 Plastic Package.

600mA
Collector currents to 600mA.

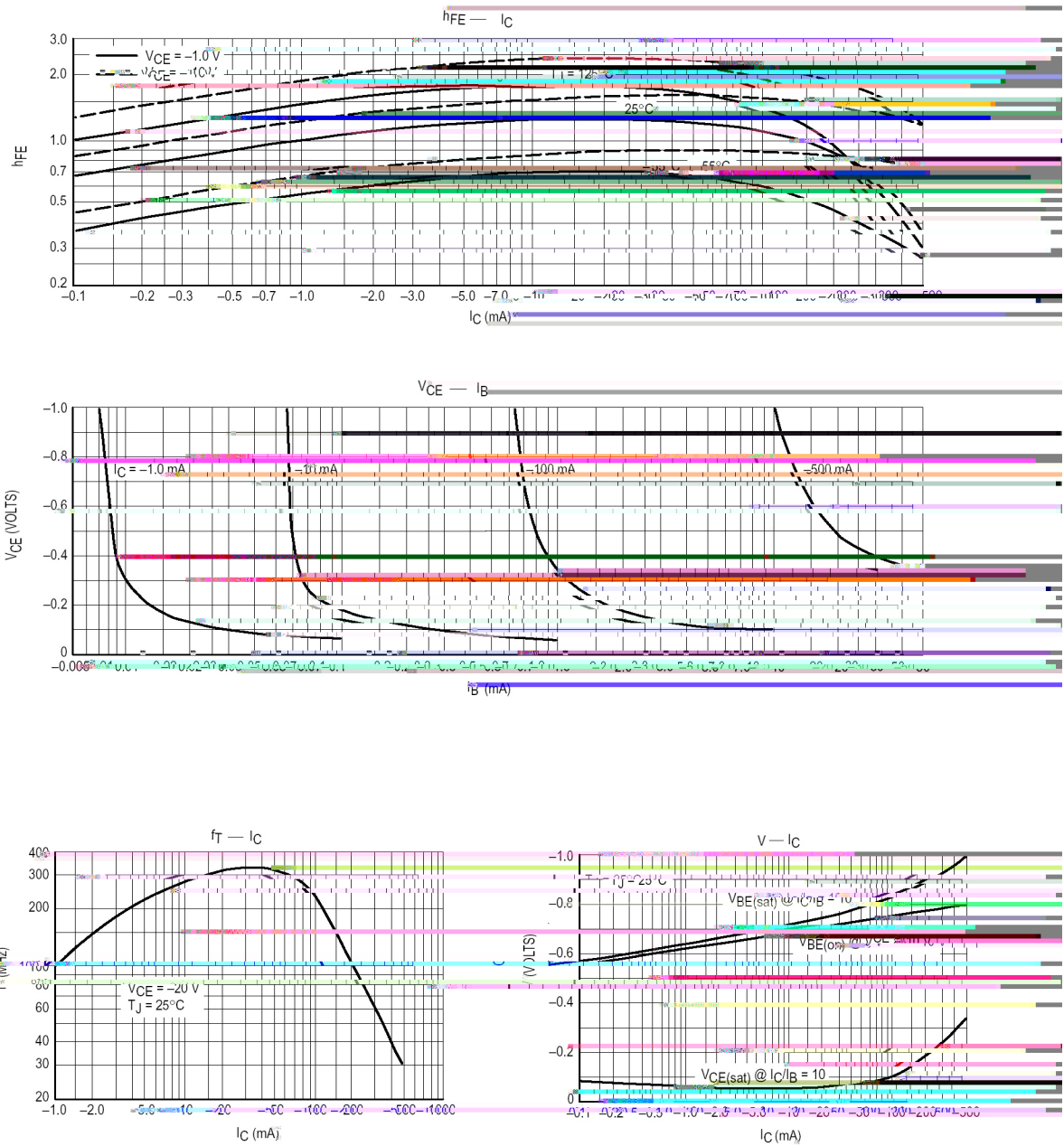
General purpose amplifier.

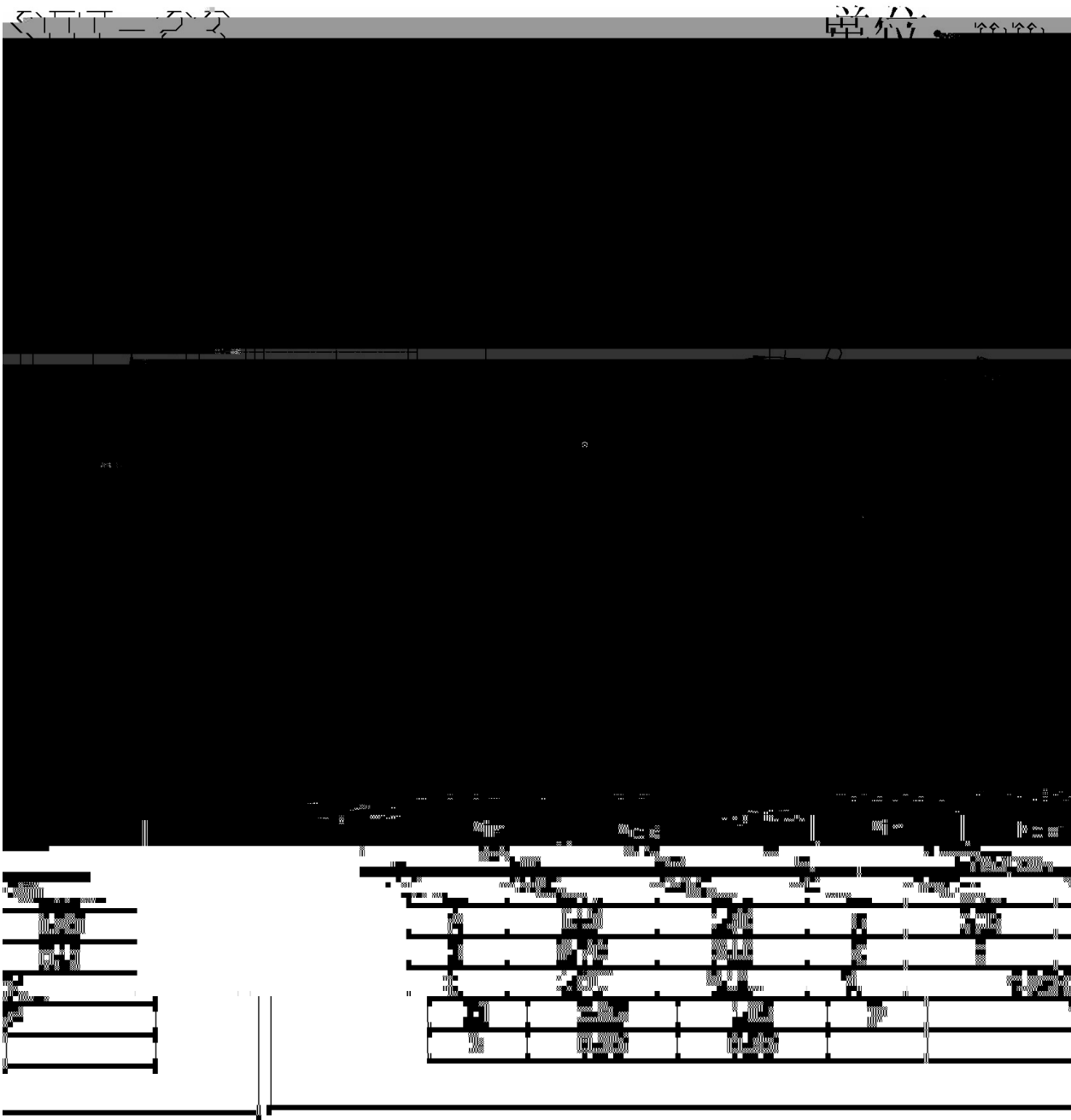


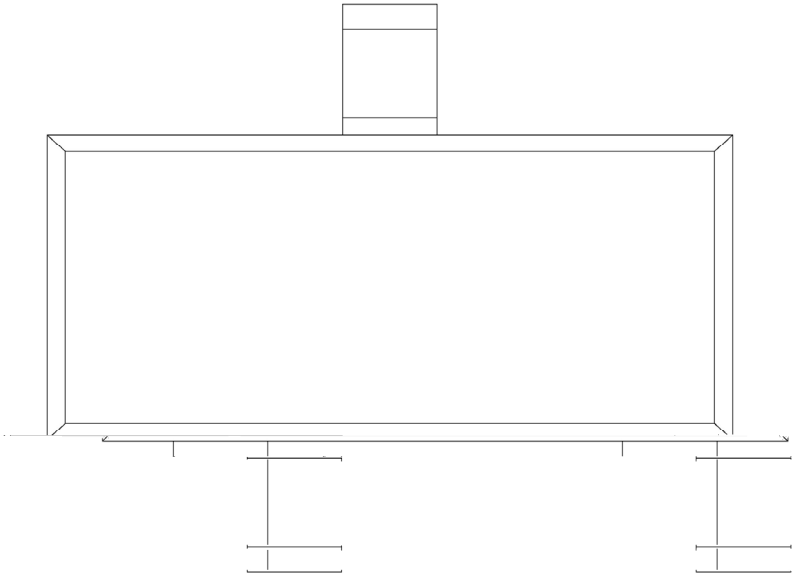
PIN 1 Base PIN 2 Emitter PIN 3 Collector

h_{FE} Range	100 300
Marking	H2B

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-60	V
Collector to Emitter Voltage	V_{CEO}	-40	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current	I_C	-600	mA
Collector Power Dissipation	P_C	350	mW
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	





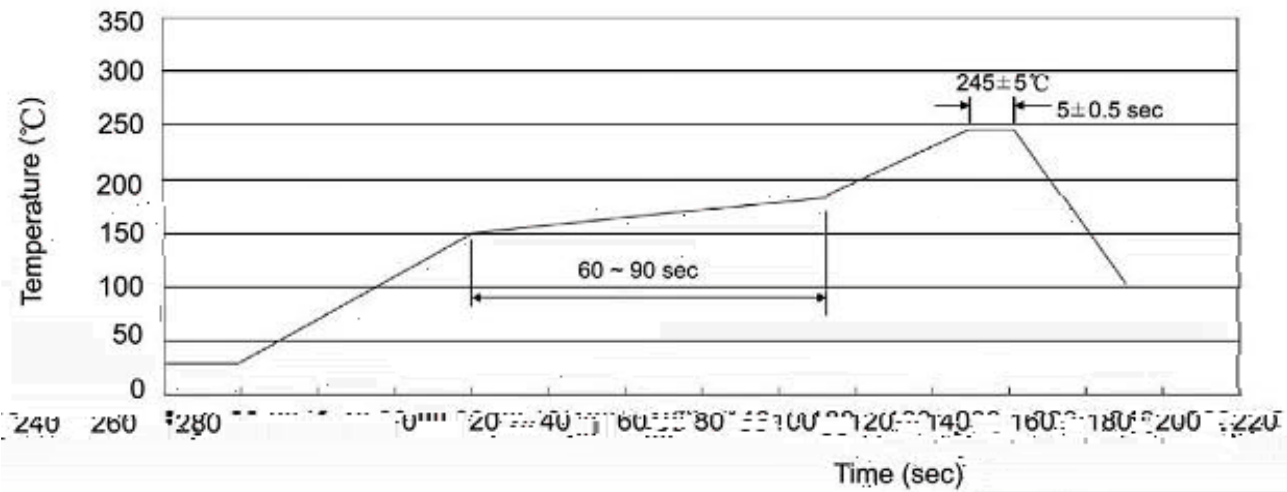


H

2B

Note:

Temperature Profile for IR Reflow Soldering(Pb-Free)



Note:

- 1

150 180

60 90sec;

1.Preheating:150~180 °C, Time:60~90sec.
- 2

245±5

5±0.5sec;

2.Peak Temp.:245±5 °C, Duration:5±0.5sec.
- 3

2 10

/sec.

3. Cooling Speed: 2~10 °C/sec.

260±5

10±1 sec.

Temp.:260±5

Time:10±1 sec

/ REEL

Package Type 封装形式	Units 包装数量				Dimension 包装尺寸 (unit: mm ³)
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	